

# 2SC3930

Silicon NPN epitaxial planer type

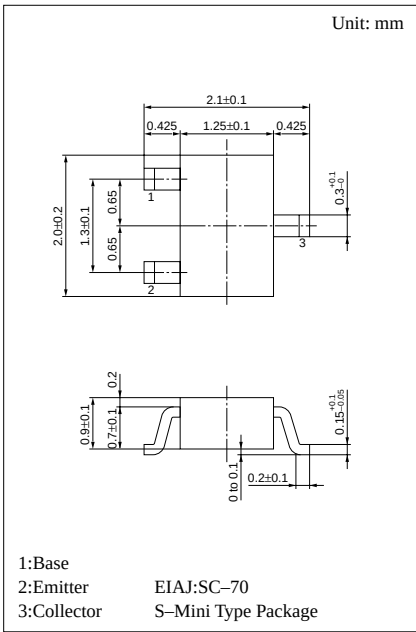
For high-frequency amplification  
Complementary to 2SA1532

## ■ Features

- Optimum for RF amplification of FM/AM radios.
- High transition frequency  $f_T$ .
- S-Mini type package, allowing downsizing of the equipment and automatic insertion through the tape packing and the magazine packing.

## ■ Absolute Maximum Ratings (Ta=25°C)

| Parameter                    | Symbol    | Ratings    | Unit |
|------------------------------|-----------|------------|------|
| Collector to base voltage    | $V_{CBO}$ | 30         | V    |
| Collector to emitter voltage | $V_{CEO}$ | 20         | V    |
| Emitter to base voltage      | $V_{EBO}$ | 5          | V    |
| Collector current            | $I_C$     | 30         | mA   |
| Collector power dissipation  | $P_C$     | 150        | mW   |
| Junction temperature         | $T_j$     | 150        | °C   |
| Storage temperature          | $T_{stg}$ | -55 ~ +150 | °C   |



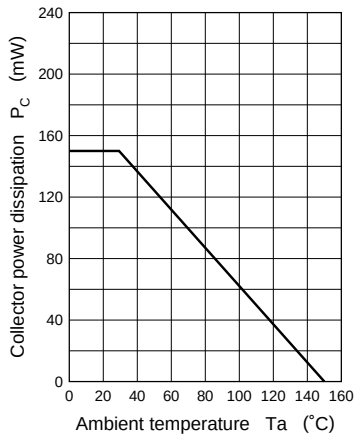
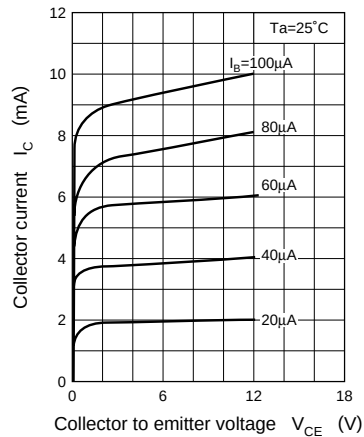
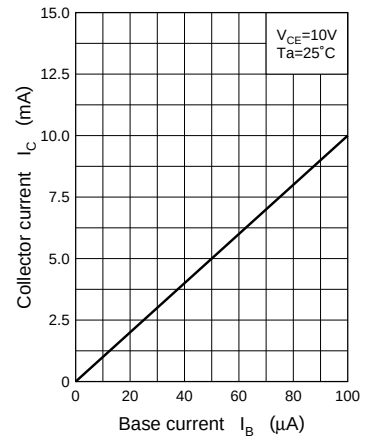
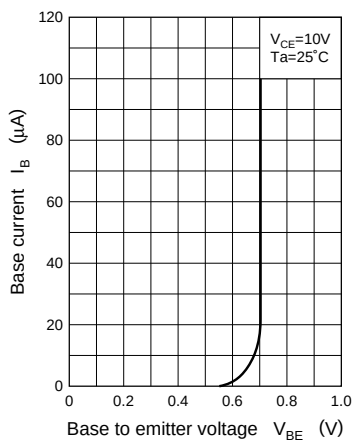
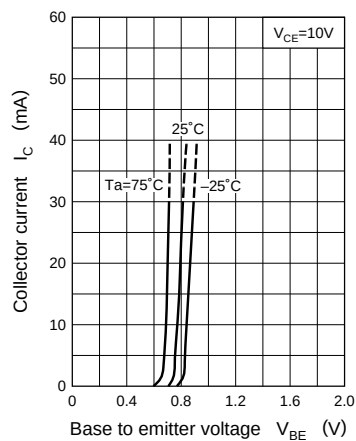
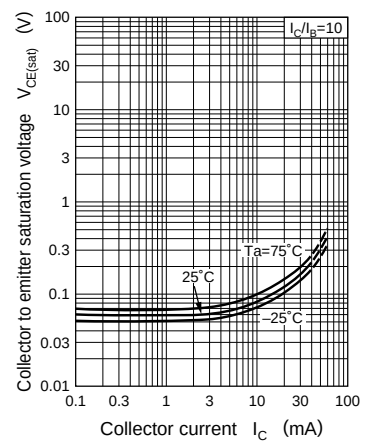
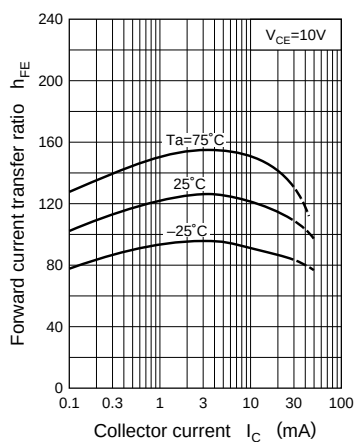
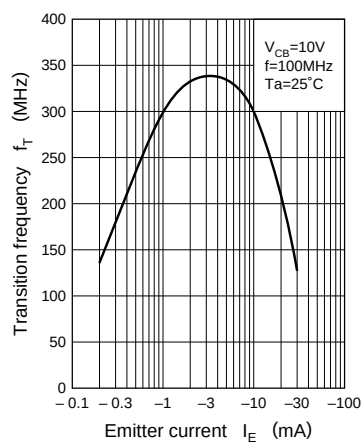
Marking symbol : V

## ■ Electrical Characteristics (Ta=25°C)

| Parameter                                   | Symbol     | Conditions                             | min | typ | max | Unit     |
|---------------------------------------------|------------|----------------------------------------|-----|-----|-----|----------|
| Collector cutoff current                    | $I_{CBO}$  | $V_{CB} = 10V, I_E = 0$                |     |     | 0.1 | $\mu A$  |
| Forward current transfer ratio              | $h_{FE}^*$ | $V_{CB} = 10V, I_E = -1mA$             | 70  |     | 220 |          |
| Transition frequency                        | $f_T$      | $V_{CB} = 10V, I_E = -1mA, f = 200MHz$ | 150 | 250 |     | MHz      |
| Noise figure                                | NF         | $V_{CB} = 10V, I_E = -1mA, f = 5MHz$   |     | 2.8 | 4   | dB       |
| Reverse transfer impedance                  | $Z_{rb}$   | $V_{CB} = 10V, I_E = -1mA, f = 2MHz$   |     | 22  | 50  | $\Omega$ |
| Common emitter reverse transfer capacitance | $C_{re}$   | $V_{CE} = 10V, I_C = 1mA, f = 10.7MHz$ |     | 0.9 | 1.5 | pF       |

\* $h_{FE}$  Rank classification

| Rank           | B        | C         |
|----------------|----------|-----------|
| $h_{FE}$       | 70 ~ 140 | 110 ~ 220 |
| Marking Symbol | VB       | VC        |

$P_C - T_a$  $I_C - V_{CE}$  $I_C - I_B$  $I_B - V_{BE}$  $I_C - V_{BE}$  $V_{CE(sat)} - I_C$  $h_{FE} - I_C$  $f_T - I_E$  $Z_{rb} - I_E$ 